

13 μ A/ch, Rail-to-Rail Output Quad CMOS Operational Amplifier

■ GENERAL DESCRIPTION

The **NJU7028** is a low power, quad CMOS operational amplifier. It is tolerant to RF noise. The NJU7028 can operate from a single-supply voltage of +1.8V to +5.5V. In addition, this amplifier features Rail-to-Rail output and low input bias current (1pA). Because of these features, the NJU7028 is ideal for low-side current sense amplifier. The very low supply current of the NJU7028 (13 μ A/ch) makes it suitable for battery-operated application.

■ PACKAGE OUTLINE



**NJU7028V
(SSOP14)**

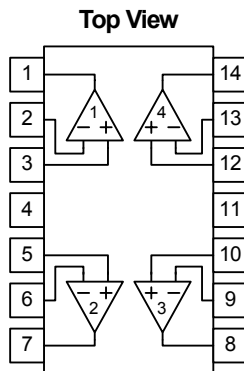
■ FEATURES

- Low Supply Current I_{DD} =13 μ A/ch typ.
- Low Operating Voltage V_{opr} = 1.8V to 5.5V
- Rail-to-Rail Output V_{OH} =4.9V min./ V_{OL} =0.1V max. (at V_{DD} = 5V, R_L =100k Ω)
 V_{OH} =4.8V min./ V_{OL} =0.2V max. (at V_{DD} = 5V, I_o =1mA)
- Enhanced RF Noise Immunity
- CMOS Process
- Package SSOP14

■ APPLICATION

- Battery-operated application
- Battery monitor
- Current sensor
- Photodiode amplification

■ PIN CONFIGURATION



Pin Function

- | | |
|-------------|--------------|
| 1. OUTPUT 1 | 8. OUTPUT 3 |
| 2. -INPUT 2 | 9. -INPUT 3 |
| 3. +INPUT 2 | 10. +INPUT 3 |
| 4. V_{DD} | 11. V_{SS} |
| 5. +INPUT 2 | 12. +INPUT 4 |
| 6. -INPUT 2 | 13. -INPUT 4 |
| 7. OUTPUT 2 | 14. OUTPUT 4 |

■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C, unless otherwise noted.)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V _{DD}	+7	V
Input Common Mode Voltage	V _{ICM}	V _{SS} -0.3 to V _{DD} +0.3	V
Differential Input Voltage	V _{ID}	±7 (Note1)	V
Power Dissipation	P _D	400 (Note2)	mW
Operating Temperature Range	T _{opr}	-40 to +85	°C
Storage Temperature Range	T _{stg}	-55 to +125	°C

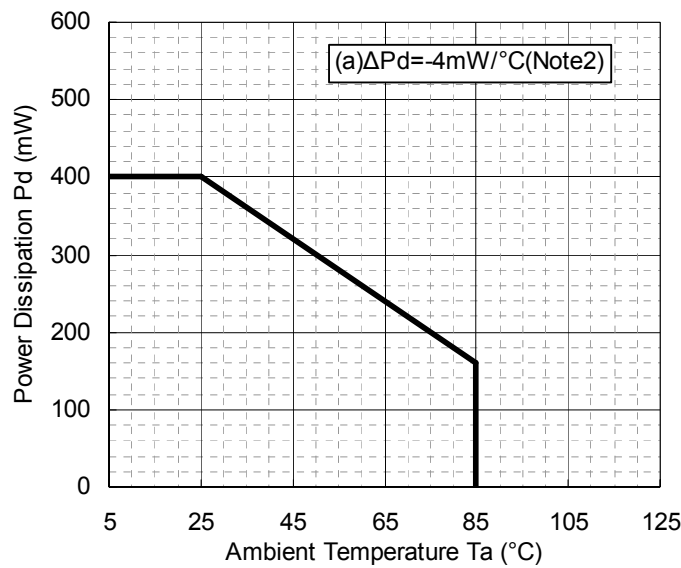
(Note1) For supply voltage less than +7V, the absolute maximum rating is equal to the supply voltage.

(Note2) EIA/JEDEC STANDARD Test board (114.3 x 76.2 x 1.6mm, 2layers, FR-4) mounting.

(Note3) Do not exceed "Power dissipation: P_D" in which power dissipation in IC is shown by the absolute maximum rating.
See Figure "Power Dissipation Curve" when ambient temperature is over 25°C.

Figure 1

Power Dissipation Derating Curve



■ RECOMMENDED OPERATING CONDITION (Ta=25°C)

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V _{DD}	1.8 to 5.5	V

■ ELECTRICAL CHARACTERISTICS

●DC CHARACTERISTICS ($V_{DD}=5V$, $V_{SS}=0V$, $T_a=25^\circ C$, unless otherwise noted.)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Current	I_{DD}	No Signal	-	48	72	μA
Input Offset Voltage	V_{IO}	$V_{IC}=0V$, $R_S=50\Omega$	-	0.9	4	mV
Input Offset Voltage drift	$\Delta V_{IO}/\Delta T$		-	1.5	-	$\mu V/^\circ C$
Input Bias Current	I_B		-	1	-	pA
Input Offset Current	I_{IO}		-	1	-	pA
Open loop gain	A_V	$V_O=0.5V$ to $4.5V$, $R_L=100k\Omega$ to $2.5V$	70	90	-	dB
Common Mode Rejection Ratio	CMR	$V_{ICM}=0V$ to $4.1V$	65	80	-	dB
Supply Voltage Rejection Ratio	SVR	$V_{DD}=1.8V$ to $5.5V$	70	90	-	dB
Maximum Output Voltage 1	V_{OH1}	$R_L=100k\Omega$ to $2.5V$	4.9	4.95	-	V
	V_{OL1}	$R_L=100k\Omega$ to $2.5V$	-	0.05	0.1	V
Maximum Output Voltage 2	V_{OH2}	$R_L=100k\Omega$ to $0V$	4.9	4.95	-	V
	V_{OL2}	$R_L=100k\Omega$ to $0V$	-	0.02	0.05	V
Maximum Output Voltage 3	V_{OH3}	$I_{source}=1mA$	4.8	4.85	-	V
	V_{OL3}	$I_{sink}=1mA$	-	0.15	0.2	V
Common Mode Input Voltage Range	V_{ICM}	CMR \geq 65dB	0	-	4.1	V

●AC CHARACTERISTICS ($V_{DD}=5V$, $V_{SS}=0V$, $T_a=25^\circ C$, unless otherwise noted.)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gain Bandwidth Product	GBW	$R_L=100k\Omega$ to $2.5V$, $C_L=20pF$, $f=10kHz$	-	160	-	kHz
Phase Margin	ϕ_M	$R_L=100k\Omega$ to $2.5V$, $C_L=20pF$	-	80	-	deg
Gain Margin	G_M	$R_L=100k\Omega$ to $2.5V$, $C_L=20pF$	-	15	-	dB
Equivalent Input Noise Voltage	e_n	$f=1kHz$	-	50	-	nV/ \sqrt{Hz}
Slew Rate	SR	$G_V=0dB$, $R_L=100k\Omega$ to $2.5V$, $C_L=20pF$, $V_{in}=3V_{pp}$ (1V to 4V) (Note4) (Note5)	-	0.05	-	V/ μs
Power Bandwidth	PBW	$G_V=6dB$, $R_F=50k\Omega$, $R_G=50k\Omega$, $C_L=20pF$, $V_{in}=2.5V_{pp}$ (1.25V to 3.75V), $V_o\geq 4.8V_{pp}$ (Note6)	-	5	-	kHz
Total Harmonic Distortion	THD	$G_V=6dB$, $R_F=50k\Omega$, $R_G=50k\Omega$, $C_L=20pF$, $V_o=4V_{pp}$, $f=100Hz$ (Note6)	-	0.01	-	%

(Note4) Slew rate is defined by the lower value of the rise or fall.

(Note5) See figure2-1 for test circuit.

(Note6) See figure2-3 for test circuit.

■ ELECTRICAL CHARACTERISTICS

●DC CHARACTERISTICS ($V_{DD}=3V$, $V_{SS}=0V$, $T_a=25^{\circ}C$, unless otherwise noted.)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Current	I_{DD}	No Signal	-	45	68	μA
Input Offset Voltage	V_{IO}	$V_{IC}=0V$, $R_S=50\Omega$	-	0.9	4	mV
Input Offset Voltage drift	$\Delta V_{IO}/\Delta T$		-	1.5	-	$\mu V/^{\circ}C$
Input Bias Current	I_B		-	1	-	pA
Input Offset Current	I_{IO}		-	1	-	pA
Open loop gain	A_V	$V_O=0.5V$ to $2.5V$, $R_L=100k\Omega$ to $1.5V$	70	90	-	dB
Common Mode Rejection Ratio	CMR	$V_{ICM}=0V$ to $2.1V$	65	80	-	dB
Supply Voltage Rejection Ratio	SVR	$V_{DD}=1.8V$ to $5.5V$	70	90	-	dB
Maximum Output Voltage 1	V_{OH1}	$R_L=100k\Omega$ to $1.5V$	2.9	2.95	-	V
	V_{OL1}	$R_L=100k\Omega$ to $1.5V$	-	0.05	0.1	V
Maximum Output Voltage 2	V_{OH2}	$R_L=100k\Omega$ to $0V$	2.9	2.95	-	V
	V_{OL2}	$R_L=100k\Omega$ to $0V$	-	0.02	0.05	V
Maximum Output Voltage 3	V_{OH3}	$I_{source}=1mA$	2.8	2.85	-	V
	V_{OL3}	$I_{sink}=1mA$	-	0.15	0.2	V
Common Mode Input Voltage Range	V_{ICM}	CMR \geq 65dB	0	-	2.1	V

●AC CHARACTERISTICS ($V_{DD}=3V$, $V_{SS}=0V$, $T_a=25^{\circ}C$, unless otherwise noted.)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gain Bandwidth Product	GBW	$R_L=100k\Omega$ to $1.5V$, $C_L=20pF$, $f=10kHz$	-	150	-	kHz
Phase Margin	ϕ_M	$R_L=100k\Omega$ to $1.5V$, $C_L=20pF$	-	80	-	deg
Gain Margin	G_M	$R_L=100k\Omega$ to $1.5V$, $C_L=20pF$	-	15	-	dB
Equivalent Input Noise Voltage	e_n	$f=1kHz$	-	50	-	nV/\sqrt{Hz}
Slew Rate	SR	$G_V=0dB$, $R_L=100k\Omega$ to $1.5V$, $C_L=20pF$, $V_{in}=1V_{pp}$ (1V to 2V) (Note4) (Note5)	-	0.05	-	V/us
Power Bandwidth	PBW	$G_V=6dB$, $R_F=50k\Omega$, $R_G=50k\Omega$, $C_L=20pF$, $V_{in}=1.5V_{pp}$ (0.75V to 2.25V), $V_O\geq 2.8V_{pp}$ (Note6)	-	8	-	kHz
Total Harmonic Distortion	THD	$G_V=6dB$, $R_F=50k\Omega$, $R_G=50k\Omega$, $C_L=20pF$, $V_O=2V_{pp}$, $f=100Hz$ (Note6)	-	0.01	-	%

(Note4) Slew rate is defined by the lower value of the rise or fall.

(Note5) See figure2-1 for test circuit.

(Note6) See figure2-3 for test circuit.

■ ELECTRICAL CHARACTERISTICS

●DC CHARACTERISTICS ($V_{DD}=1.8V$, $V_{SS}=0V$, $T_a=25^\circ C$, unless otherwise noted.)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Current	I_{DD}	No Signal	-	43	65	μA
Input Offset Voltage	V_{IO}	$V_{ic}=0V$, $R_S=50\Omega$	-	0.9	4	mV
Input Offset Voltage drift	$\Delta V_{IO}/\Delta T$		-	1.5	-	$\mu V/^\circ C$
Input Bias Current	I_B		-	1	-	pA
Input Offset Current	I_{IO}		-	1	-	pA
Open loop gain	A_V	$V_o=0.5V$ to $2.5V$, $R_L=100k\Omega$ to $0.9V$	70	90	-	dB
Common Mode Rejection Ratio	CMR	$V_{ICM}=0V$ to $0.9V$	65	80	-	dB
Supply Voltage Rejection Ratio	SVR	$V_{DD}=1.8V$ to $5.5V$	70	90	-	dB
Maximum Output Voltage 1	V_{OH1}	$R_L=100k\Omega$ to $0.9V$	1.7	1.75	-	V
	V_{OL1}	$R_L=100k\Omega$ to $0.9V$	-	0.05	0.1	V
Maximum Output Voltage 2	V_{OH2}	$R_L=100k\Omega$ to $0V$	1.7	1.75	-	V
	V_{OL2}	$R_L=100k\Omega$ to $0V$	-	0.02	0.05	V
Maximum Output Voltage 3	V_{OH3}	$I_{source}=0.5mA$	1.5	1.55	-	V
	V_{OL3}	$I_{sink}=0.5mA$	-	0.25	0.3	V
Common Mode Input Voltage Range	V_{ICM}	CMR \geq 65dB	0	-	0.9	V

●AC CHARACTERISTICS ($V_{DD}=1.8V$, $V_{SS}=0V$, $T_a=25^\circ C$, unless otherwise noted.)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gain Bandwidth Product	GBW	$R_L=100k\Omega$ to $0.9V$, $C_L=20pF$, $f=10kHz$	-	140	-	kHz
Phase Margin	ϕ_M	$R_L=100k\Omega$ to $0.9V$, $C_L=20pF$	-	80	-	deg
Gain Margin	G_M	$R_L=100k\Omega$ to $0.9V$, $C_L=20pF$	-	15	-	dB
Equivalent Input Noise Voltage	e_n	$f=1kHz$	-	50	-	nV/\sqrt{Hz}
Slew Rate	SR	$G_V=0dB$, $R_L=100k\Omega$ to $1.5V$, $C_L=20pF$, $V_{in}=0.5V_{pp}$ ($0.3V$ to $0.8V$) (Note4) (Note7)	-	0.05	-	V/us
Power Bandwidth	PBW	$G_V=6dB$, $R_F=50k\Omega$, $R_G=50k\Omega$, $C_L=20pF$, $V_{in}=0.9V_{pp}$ ($0V$ to $0.9V$), $V_o\geq 1.6V_{pp}$ (Note8)	-	14	-	kHz
Total Harmonic Distortion	THD	$G_V=6dB$, $R_F=50k\Omega$, $R_G=50k\Omega$, $C_L=20pF$, $V_o=1V_{pp}$, $f=100Hz$ (Note8)	-	0.01	-	%

(Note4) Slew rate is defined by the lower value of the rise or fall.

(Note7) See figure2-2 for test circuit.

(Note8) See figure2-4 for test circuit..

■ MEASUREMENT CIRCUITS

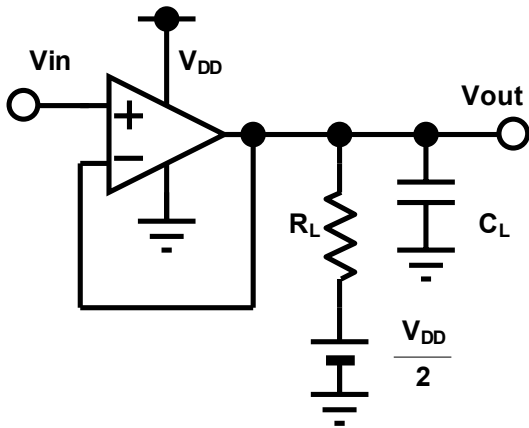


Figure 2-1: Measurement circuit 1

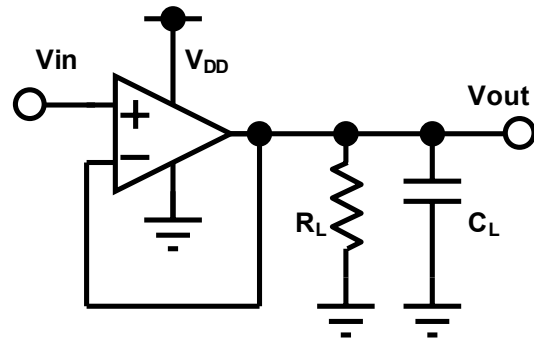


Figure 2-2: Measurement circuit 2

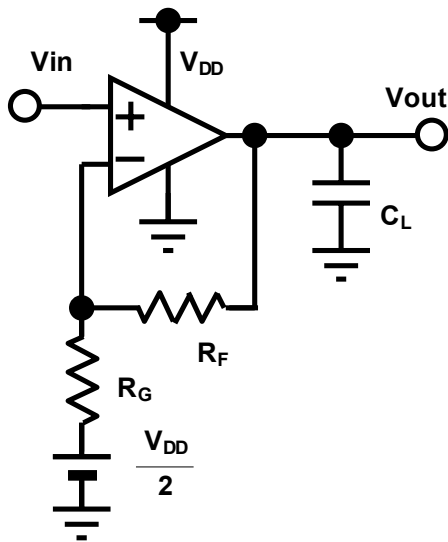


Figure 2-3: Measurement circuit 3

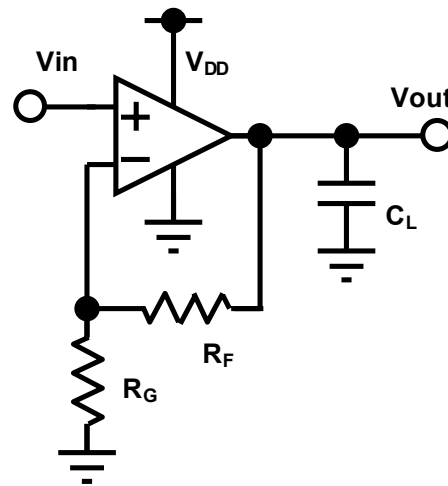
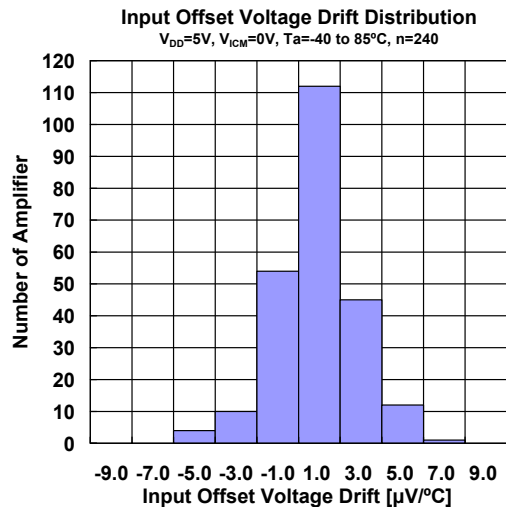
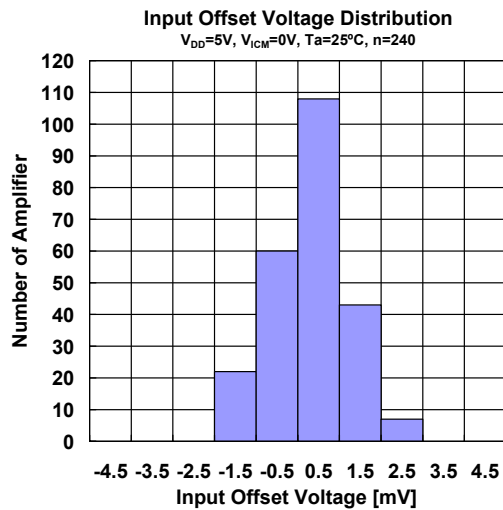
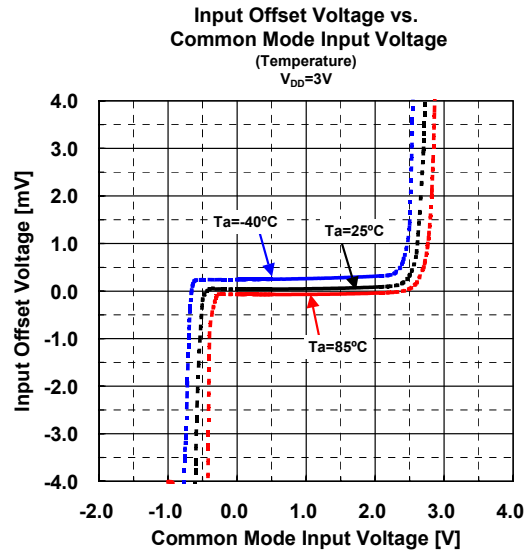
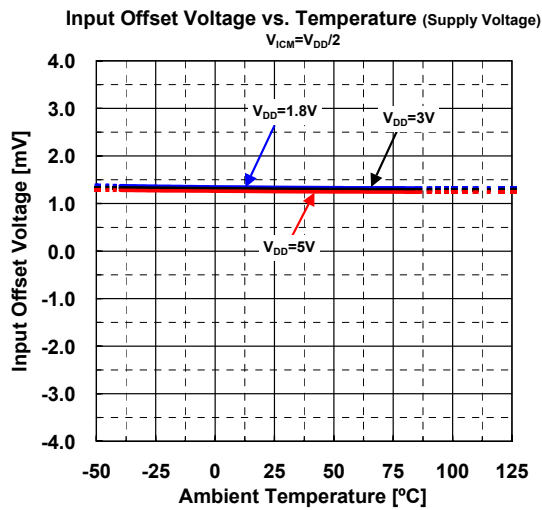
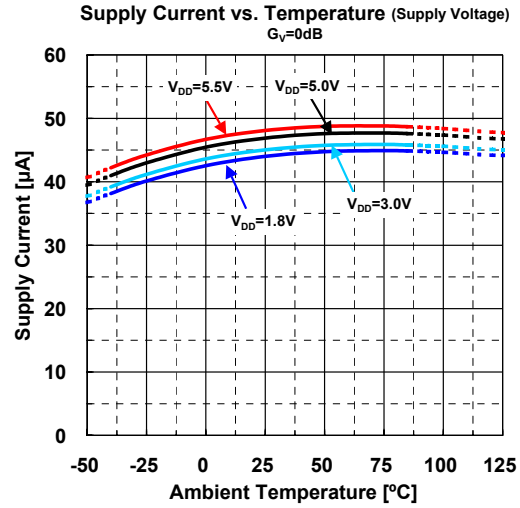
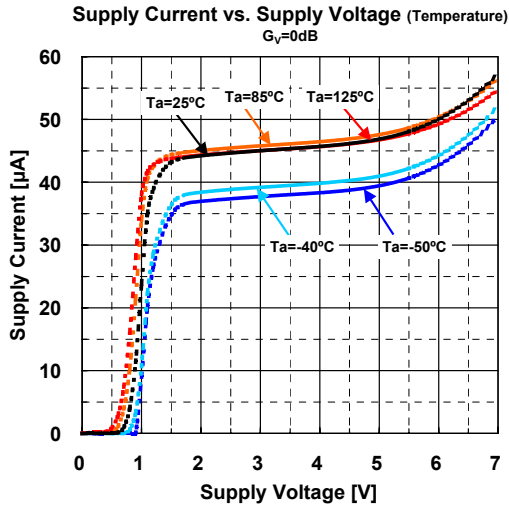
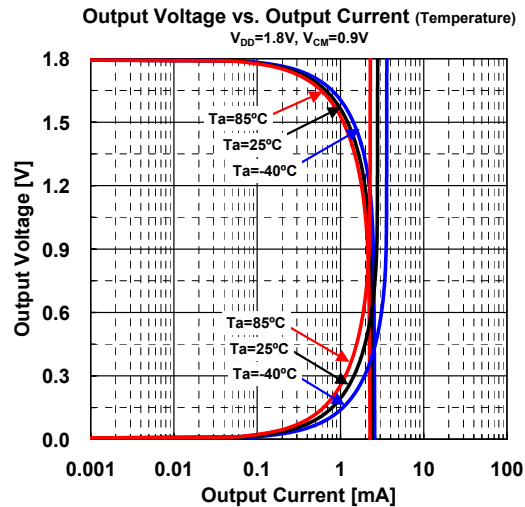
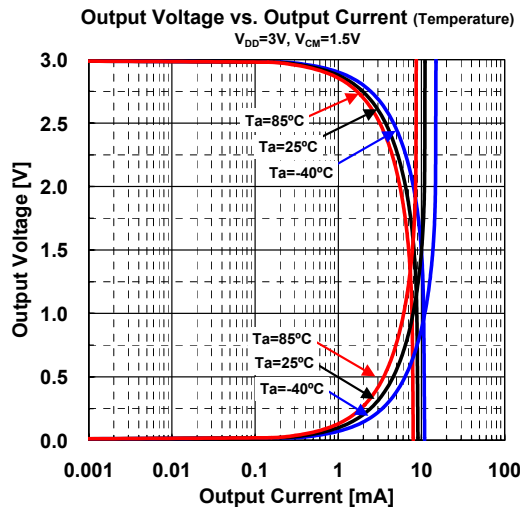
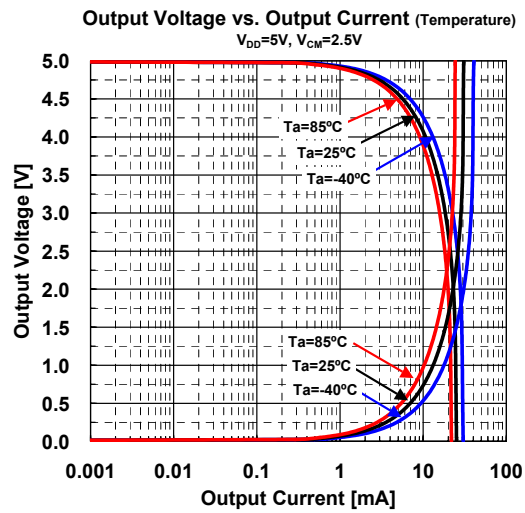
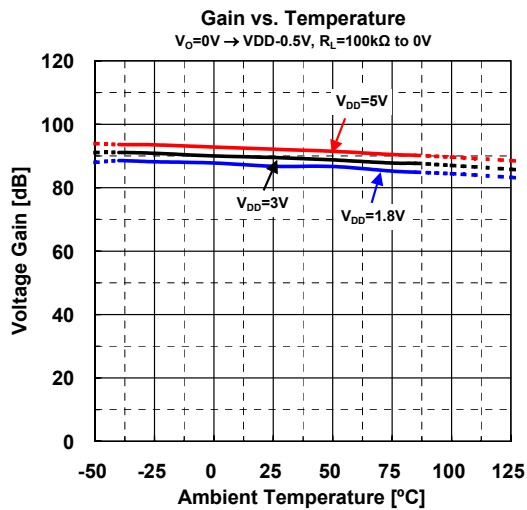
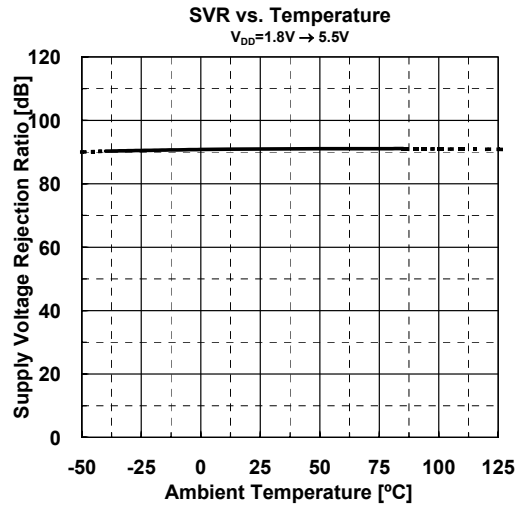
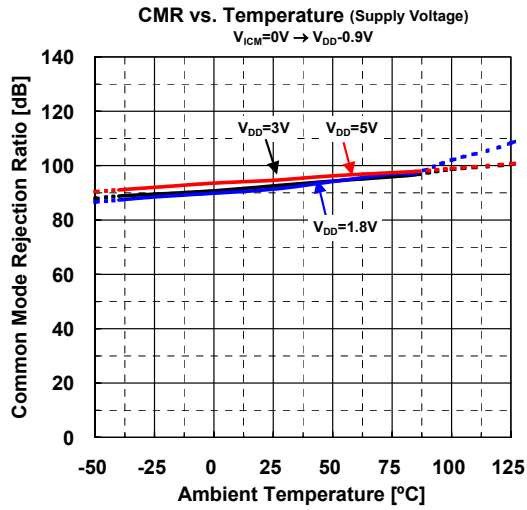


Figure 2-4: Measurement circuit 4

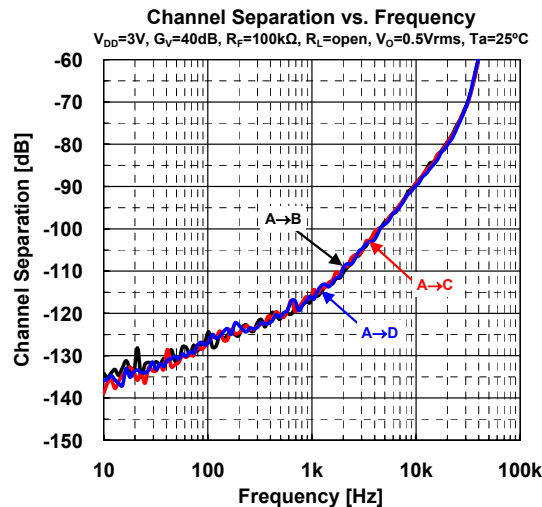
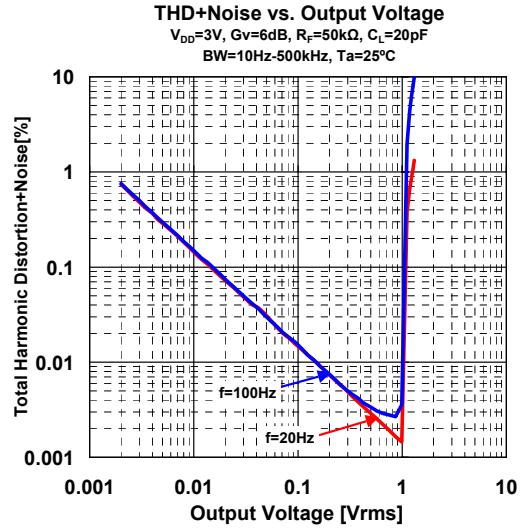
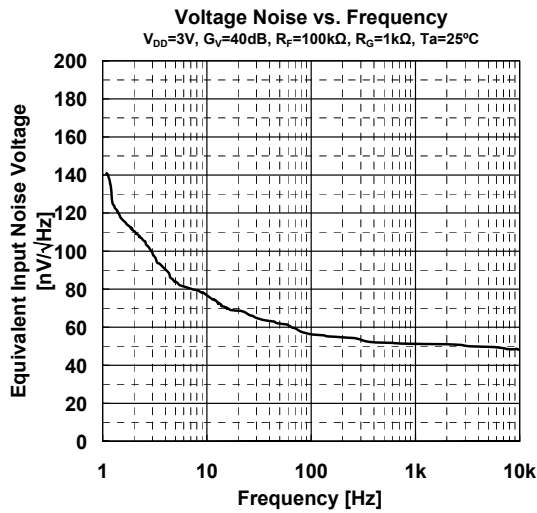
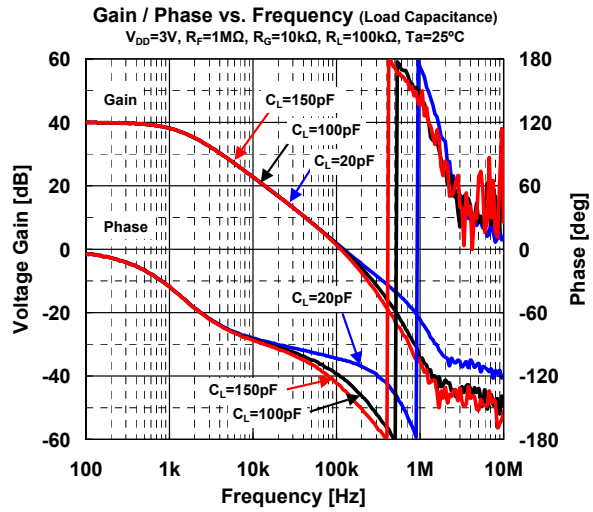
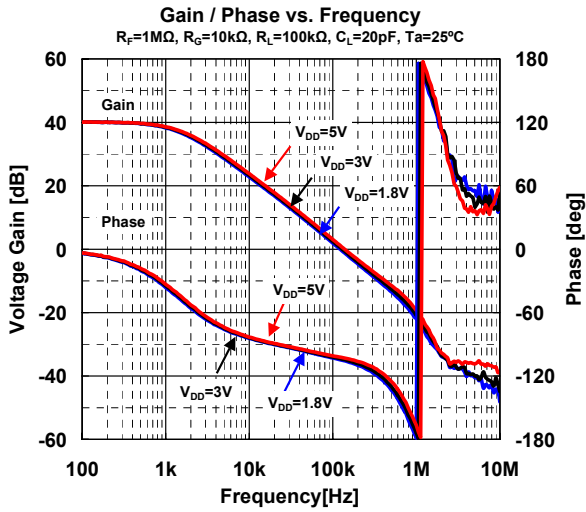
TYPICAL CHARACTERISTICS



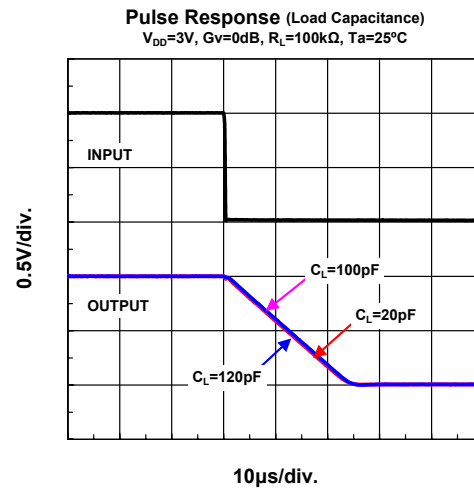
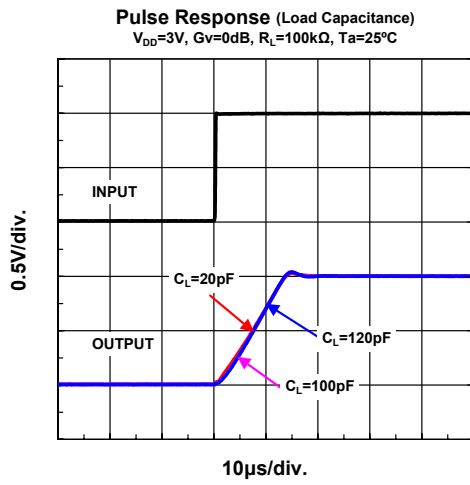
TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS



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